Transistor Silicon PNP Epitaxial Type

Power Amplifier Applications

FEATURES

- * High collector voltage: Vceo=-140V(min)
- * Recommended for 70W high-fidelity audio
 - Frequency amplifier output
- * Complementary to 2SC5198



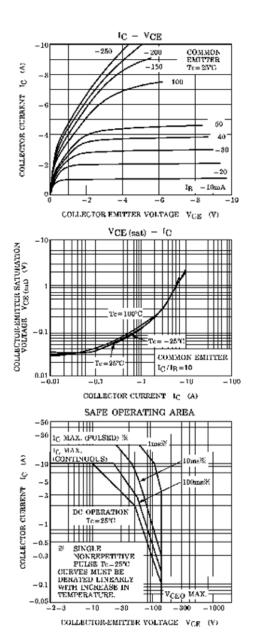
MAXIMUM RATINGS (Ta=25°C)

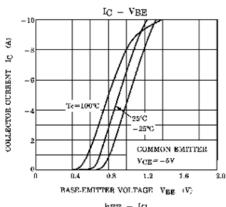
Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	V _{CEO}	-140	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector current	Ic	-10	А
Base current	I _B	-1	А
Collector Power Dissipation	Pc	100	W
Junction Temperature	TJ	150	°C
Collector-Base Voltage	T _{stg}	-55to+150	°C

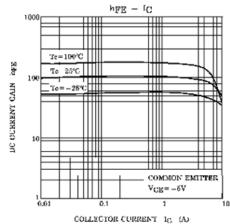
ELECTRICAL CHARACTERISTICS (Ta=25°C)

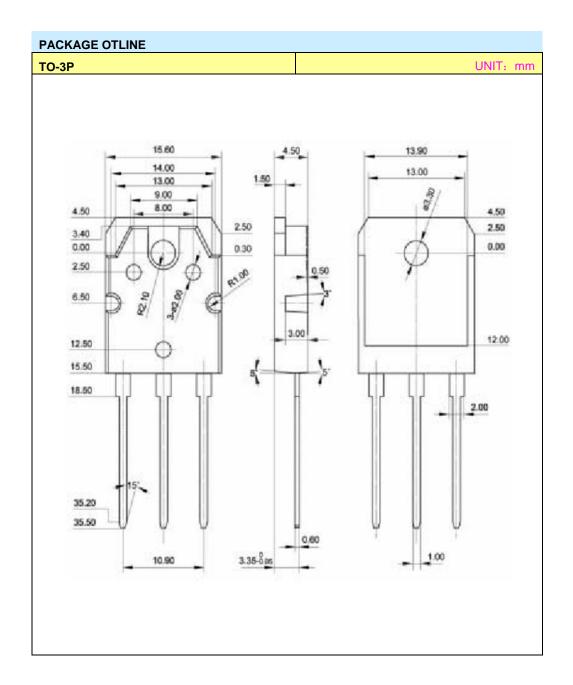
Characteristics		Symbol	Test conditions	Min	Тур	Max.	Unit
Collector Cut-off Current		I _{CBO}	Vcb=-140V,Ie=0			-5.0	uA
Emitter Cut-off Current		I _{EBO}	Veb=-5V,Ic=0			-5.0	uA
Collector-Emitter Breakdown Voltage		V_{CEO}	Ic=-50mA,Ib=0	-140			V
DC Current Gain		hfe1	Vce=-5V,Ic=-1.0A	55		160	
		hfe2	Vce=-5V,Ic=-5A	35			
Saturation Voltage	Collector- Emitter	V_{CESAT}	Ic=-7A,Ib=-0.7A			-2.0	V
Base-Emitter Voltage		V_{be}	Vce=-5V,Ic=-5A			-1.5	V
Transition Frequency		f⊤	Vce=-5V,Ic=-1A		30		MHZ
Collector Output Capacitance		C_ob	Vce=-10V, le=0,f=1MHZ		320		pF

TYPICAL PERFORMANCE CHARACTERISTICS









ELECTROSTATIC DISCHARGE CAUTION



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage handing to prevent electrostatic damage to the device.

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